## Lection5

4). Exciton photoluminescence (1h) (exciton lifetime in bulk, QW, QWW and QD, homogeneous linewidth, interaction with phonons)
5). Optical orientation and alignment (1h)
(the idea of the optical orientation; mechanisms of exciton spin relaxation, the alignment of the exciton dipole momenta, polarization conversion)

## Photoluminescence

Photoluminescence excitation


Photoluminescence

-Normally the exciton PL spectrum determine by recombination of localized exciton states.
-The main mechanism for the localization is monolayer fluctuation of the interfaces.

## Delocalized states

At high temperature excitons become delocalized

$$
f\left(K_{\|}\right)=C \exp \left(-\hbar^{2} K_{\|}^{2} / 2 M k_{B} T\right)
$$

here $\quad C \propto T^{d / 2} N \quad N-$ Number of excitons

Optically active are only excitons with $K_{\|}<\left(\omega_{0} / c\right) \sqrt{\varepsilon_{b}}$

The excitons with $K_{\|}>\left(\omega_{0} / c\right) \sqrt{\varepsilon_{b}}$ are out of the light cone

## Efficiency of the radiative recombination

$$
\left\langle\tau_{r}^{-1}\right\rangle=\frac{\int d \mathbf{K}_{\|} \tau_{r}^{-1}\left(K_{\|}\right) f\left(K_{\|}\right)}{\int d \mathbf{K}_{\|} f\left(K_{\|}\right)} \propto \frac{C}{N} \propto T^{d / 2}
$$

Homogeneous linewidth at high temperature


Line width QWs

$$
\frac{\Delta E}{E} \propto 2 \frac{\Delta L}{L}
$$

## Resonant fluorescence and Raman scattering

Two level systems. Spectral intensity:

$$
\begin{gathered}
I\left(e_{2}, \omega_{2} \mid e_{1}, \omega_{1}\right) \propto|M|^{2} \delta\left(\omega_{2}-\omega_{1}\right) \\
M \propto \frac{\left(\vec{e}_{2}^{*} \vec{d}_{i f}\right)\left(\vec{e}_{1} \vec{d}_{f i}\right)}{\omega_{0}-\omega-i \Gamma} E_{0} \\
\Gamma=\frac{1}{2 \tau_{f}} \quad \tau_{f} \text { is the lifetime of the excited state }
\end{gathered}
$$

-Delocalized excitons can recombine radiativly only incise light cone $K<(\omega / c) \sqrt{\varepsilon_{b}}$

- At high temperature excitons delocalized and
linewidth becomes homogeneous
- At resonant excitation two processes are undistinguishing:

Raman scattering and resonant fluorescence

## Localized states


-There are jumps of excitons over these states -The PL spectrum forms due to competition between recombination and relaxation

## Photoluminescence, Stokes shift

Stokes shift: $E=E_{0}-\mathcal{E} \quad ; \quad$ Mobility edge $E_{0}$
Mobility edge separates extended and localized states

1. The density of localized states is exponential
(number of shallow wells is large)

$$
g(\varepsilon)=g_{0} \exp \left(-\varepsilon / \varepsilon_{0}\right)
$$

2. Exciton hopping transfer rate between localized states
(probability of the jump defined by distance only)

$$
\omega\left(\varepsilon, \varepsilon^{\prime}, r\right)=\theta\left(\varepsilon-\varepsilon^{\prime}\right) \omega_{h}(r)
$$

3. The rate $\omega_{h}(r)$ is independent of $\mathcal{E}$ and $\mathcal{E}^{\prime}$, and decays exponentially because it is the tale of wavefunction

$$
\omega_{h}(r)=\omega_{0} e^{-2 r / L}
$$

The PL peak $\quad E_{\text {max }}=E-\mathcal{E}_{\text {max }}$ and the delay time $\boldsymbol{t}$ (at pulse excitation) is

$$
\tau_{\varepsilon_{\max }}=\omega_{0}^{-1} \exp \left(2 \bar{r}_{\varepsilon} / L\right)=t
$$

$$
\mathcal{E}_{\max }(t)=\varepsilon_{0} \ln \left[g_{0} \varepsilon_{0} V_{d}(L / 2) \ln \left(\omega_{0} t\right)\right]=
$$

$$
d \varepsilon_{0} \ln \ln \left(\omega_{0} t\right)+A
$$

where $A=\varepsilon_{0} \ln \left[g_{0} \varepsilon_{0} V_{d}(L / 2)\right]$
At CW excitation $t \leftrightarrow \tau_{0}$ recombination time

$$
\mathcal{E}_{\text {max }}^{c w}(t)=d \mathcal{E}_{0} \ln \ln \left(\omega_{0} \tau_{0}\right)+A
$$

4. The recombination time is independent of $\varepsilon$

Concentration of the states with energy exceeds $\mathcal{E}$ is

$$
\rho(\varepsilon)=\int_{\varepsilon}^{\infty} d \varepsilon^{\prime} g\left(\varepsilon^{\prime}\right)=g_{0} \varepsilon_{0} e^{-\varepsilon / \varepsilon_{0}}
$$

Localized exciton onto the site $\mathcal{E}$ hopes within $\bar{r}_{\varepsilon}$
Average distance $\bar{r}_{\varepsilon}$ between localized states with $\mathcal{E}^{\prime}>\mathcal{E}$

$$
V_{d}\left(\bar{r}_{\varepsilon}\right) \rho(\varepsilon)=1
$$

Lifetime with respect to hopping

$$
\tau_{\varepsilon}=\omega_{h}^{-1}\left(\bar{r}_{\varepsilon}\right)=\omega_{0} e^{2 \bar{r}_{\varepsilon} / L}
$$



Fig. 5.1. The temporal shift of the PL peak measured at $T=2 \mathrm{~K}$ in the $20 \AA$ $\mathrm{Zn}_{0.8} \mathrm{Cd}_{0.2} \mathrm{Se} / \mathrm{ZnSe} \mathrm{QW}$ and calculated from (5.30) with the values of parameters indicated in the text. The dashed horizontal line indicates the position of the PL peak under steady-state excitation. [5.3]
-In the PL always Stokes shift
-The Stokes shift defined by competition between Relaxation and recombination

## Principe of electron optical orientation

1). At interband optical transitions the angular momentum of photon transforms into the angular momentum of exciton

$$
\begin{aligned}
& \frac{n_{+}}{\tau_{0}}+\frac{1}{2 \tau_{s}}\left(n_{+}-n_{-}\right)=G_{+} \\
& \frac{n_{-}}{\tau_{0}}+\frac{1}{2 \tau_{s}}\left(n_{-}-n_{+}\right)=G_{-}
\end{aligned}
$$

Here $G_{ \pm}$is generation rate
$\tau_{0}$ is lifetime
$\tau_{s}$ is spin relaxation time

$$
\begin{array}{lll}
\text { Notify } & n=n_{+}+n_{-} & \text {Total number of electrons } \\
& G=G_{+}+G_{-} & \text {Generation rate } \\
s_{z}=\left(n_{+}+n_{-}\right) / 2 & \text { Average spin } \\
p=\frac{n_{+}-n_{-}}{n_{+}+n_{-}} & \text {Degree of polarization } \\
& S_{z}=s_{z} / n=p / 2 & \text { Average spin of one electron }
\end{array}
$$

The solution of the equations

$$
\begin{aligned}
& p=p_{0}\left(\frac{T}{\tau_{0}}\right) \\
& p_{0}=\frac{G_{+}-G_{-}}{G_{+}+G_{-}}, \quad \frac{1}{T}=\frac{1}{\tau_{0}}+\frac{1}{\tau_{s}}
\end{aligned}
$$

$$
T \text { is spin lifetime }
$$

2). Oriented spins conserve their polarization (in part) at a steady state pumping

$$
S_{z}=\frac{\tau_{s}}{\tau_{0}+\tau_{s}} S_{z}^{0}, \quad S_{z}^{0}=\frac{1}{2} p_{0}
$$

The initial spin polarization is proportional to the polarization of excited light $p_{0}=\kappa P_{c}^{0}$
$\kappa$ Depends on the selection rules
For bulk GaAs $\kappa=-1 / 2$
For QW $\kappa=-1$
3). Due to the same selection rules the ptotoluminecsence is partially polarized

$$
P_{c}=\kappa p=\kappa^{2} P_{c}^{0} \frac{T}{\tau_{0}}
$$

4). Transverse magnetic field lead to depolarization of the PL (Hanle effect)
The kinetic equations $\frac{n}{\tau_{0}}=G, \quad\left(\frac{1}{\tau_{0}}+\frac{1}{\tau_{s}}\right) \mathbf{s}+\mathbf{s} \times \boldsymbol{\Omega}_{L}=\dot{\mathbf{s}}$
$\boldsymbol{\Omega}_{L}$ Is Larmour frequency

$$
\frac{s_{x}}{T}=s_{x}, \quad \frac{s_{y}}{T}+\Omega_{L} s_{z}=\dot{s}_{y}, \quad \frac{s_{z}}{T}-\Omega_{L} s_{y}=\dot{s}_{z}
$$

## Hanle Effect

$$
s_{z}(B)=\frac{s_{z}(0)}{1+\left(\Omega_{L} T\right)^{2}}
$$

$$
s_{y}(B)=\frac{\Omega_{L} T}{1+\left(\Omega_{L} T\right)^{2}} s_{z}(0)
$$



-In optical orientation an angular momentum of the photon transfer to the electron -Effect Hanle is a stroboscopic effect and allows to determin lifetime and spin relaxation time in CW experiment -This method is used for optically detected paramagnetic resonance, optically detected nuclear magnetic resonance, optical cooling, etc.

## Electron spin relaxation mechanisms

1). Elliott - Yaffet (EY) mechanism. Mixing opposite spin states from other bands by $(\mathbf{K} \mathbf{p})$ perturbation
2). Beer-Ahronov-Pikus (BDP). Electron hole scattering with spin flip
3). D'yakonov and Perel (DP). Precession of the electron spin in an effective qusi-magnetic field without inversion symmetry
4). Fluctuation of nuclear spins in QDs
-EY is important in narrow gap semiconductors like InSb In QWs EY is important for holes.
-BAP is important for doped structures at low temperatures.
-DP is important in wide array of optical nanostructures

## Dependence of the main spin on the excitation energy in QWs



Fig. 9.7. Dependence of the mean spin of excited electrons on the quantity $t_{h}=$ $k_{\perp}^{2} /\left(k_{\perp}^{2}+k_{z}^{2}\right)$ for transitions to the first electronic level from the lowest levels of heavy (curve 1) and light (curve 2) holes (after [9.32])

Remain the band structure of cubic semiconductors
In the conductivity band (diamond)


$$
\begin{gathered}
\varphi_{\mathbf{k}, m}^{e}=u_{m} e^{i \mathbf{k r}}, \quad m= \pm 1 / 2 \\
u_{1 / 2}=S(r) \uparrow, \quad u_{-1 / 2}=S(r) \downarrow \\
\text { At } \quad \Gamma^{\text {point }} \\
\mathcal{E}_{e}(k)=\hbar^{2} k^{2} / 2 m_{e}
\end{gathered}
$$

No inversion symmetry
$\boldsymbol{\mathcal { E }}_{e}(k)=\frac{\hbar^{2} k^{2}}{2 m_{e}}+\frac{\hbar^{2}}{2}(\vec{\sigma} \vec{\Omega})$
$\Omega_{x}(\mathrm{k})=\alpha \hbar^{2}\left(m_{e} \sqrt{2 m_{e} E_{g}}\right)^{-1} k_{x}\left(k_{y}^{2}-k_{z}^{2}\right)$

Electron Hamiltonian includes linear term in QWs

$$
\begin{gathered}
H_{s}(k)=\frac{1}{2} \vec{\sigma} \cdot \vec{\Omega}_{1} \\
\Omega_{1} \equiv \Omega_{1}(-\cos \phi, \sin \phi, 0) \quad \phi \text { is an angle between } k \text { and } x
\end{gathered}
$$

$$
\hbar \Omega_{1}=2 \gamma k\left(\left\langle k_{z}^{2}\right\rangle-\frac{1}{2} k^{2}\right)
$$

Spin relaxation time

$$
\begin{aligned}
& \frac{1}{\tau_{s, z z}^{e}}=\frac{2}{\tau_{s, x x}^{e}}=\frac{2}{\tau_{s, y y}^{e}}=\Omega_{1}^{2} \tau_{1} \\
& \frac{1}{\tau_{s, i j}^{e}}= \\
& \Omega_{1} \tau_{p} \ll 1 \\
& s_{z}(\mathrm{t})=\mathrm{s}_{z}(0) \exp \left(-\frac{t}{\tau_{s}}\right)
\end{aligned}
$$

Taking average on magnetic field

Suppression of the spin relaxation in longitudinal magnetic fields

$$
\begin{aligned}
& \frac{1}{\tau_{s, z z}^{e}}=\frac{\Omega_{1}^{2} \tau_{p}}{1+\left(\omega_{c} \tau_{p}\right)^{2}} \\
& \left(\tau_{s, z z}^{e}\right)^{-1} \quad \omega_{c}=e B / m c \\
& \text { Magnetic field }
\end{aligned}
$$

## Optical orientation in the longitudinal magnetic field

$$
s_{z}=\frac{\tau_{s}}{\tau_{0}+\tau_{s}} s_{z}(0)
$$



## Spin quantum bits

$$
\begin{aligned}
& \vec{S}(t) \equiv \vec{S}(0) \cos \left(\boldsymbol{\omega}_{L} t\right) e^{-t / \boldsymbol{\tau}_{S}} \\
& \langle\vec{S}(t)\rangle_{t}=\frac{\vec{S}_{0}}{1+\left(\boldsymbol{\omega}_{L} \boldsymbol{\varepsilon}_{S}\right)^{2}}
\end{aligned}
$$



One can separate anisotropy of g -factor and relaxation time

## Dresselhous and Rashba effective field


$\mathcal{H}_{\mathrm{BIA}}=\beta\left(\sigma_{x} k_{x}-\sigma_{y} k_{y}\right)$

$\mathcal{H}_{\text {SIA }}=\alpha\left(\sigma_{x} k_{y}-\sigma_{y} k_{x}\right)$

## Raskiba + Dresselfaus


N.S. Averkiev and L.E. Golub, Phys. Rev. B (1999)

## Hanle $\Rightarrow$ different SRT


-There are a lot of mechanisms for energy relaxation but there are only few mechanisms of angular momentum relaxation.
(For example relaxation between hole states $+\frac{3}{2} \quad$ to $-\frac{3}{2}$ $\Delta M=3$ is forbidden. But LH HH mixing leads to allowed transition $\Delta M=1$ )

## Optical orientation and optical alignment of excitons

At linearly polarized excitation in longitudinal magnetic field the polarization plane turns on

$$
\theta=\frac{1}{2} \operatorname{arctg}\left(\Omega_{\|} \tau_{0}\right)
$$

The degree of polarization $P_{\text {lin }}=\left(P_{\text {lin }}^{\prime 2}+P_{\text {lin }}^{\prime \prime 2}\right)^{1 / 2}$ decreases

$$
\text { in }\left[1+\left(\Omega_{\|} \tau_{0}\right)^{2}\right]^{1 / 2} \text { times }
$$

$$
P_{l i n}^{\prime}=\frac{\bar{d}_{x}^{2}-\bar{d}_{y}^{2}}{\bar{d}_{x}^{2}+\bar{d}_{y}^{2}}, \quad P_{l i n}^{\prime \prime}=\frac{\bar{d}_{x^{\prime}}^{2}-\bar{d}_{y^{\prime}}^{2}}{\bar{d}_{x^{\prime}}^{2}+\bar{d}_{y^{\prime}}^{2}}
$$

Consider the exciton as a classic dipole . $\mathbf{d}_{0}$ Let it excided in $\quad x$ direction. In the longitudinal $K \| B$ magnetic field it rotates around $z$ with velocity

$$
\Omega_{\|} / 2, \quad \Omega_{\|}=\Omega_{e}+\Omega_{h}, \quad \hbar \Omega=\mu g B
$$

Created at $t=0$ components of the dipole moment at $t>0$

$$
\begin{array}{ll}
d_{x}(t)=d_{0} \cos \left(\Omega_{\|} t / 2\right) & d_{x}^{\prime}(t)=d_{0} \cos \left(\Omega_{\|} t / 2-\pi / 4\right) \\
d_{y}(t)=d_{0} \sin \left(\Omega_{\|} t / 2\right) & d_{y}^{\prime}(t)=d_{0} \sin \left(\Omega_{\|} t / 2-\pi / 4\right)
\end{array}
$$

$$
\begin{gathered}
\bar{d}_{\alpha}^{2}=\frac{\int_{0}^{\infty} d t \exp \left(-t / \tau_{0}\right) d_{\alpha}^{2}(t)}{\int_{0}^{\infty} d t \exp \left(-t / \tau_{0}\right)} \\
d_{x}^{2}-d_{y}^{2}=d_{0}^{2} \cos ^{2} \Omega_{\|} t \\
d_{x^{2}}^{2}-d_{y^{2}}^{2}=d_{0}^{2} \sin ^{2} \Omega_{\|} t \\
d_{x}^{2}+d_{y}^{2}=d_{x^{2}}^{2}+d_{y^{\prime}}^{2}=d_{0}^{2}
\end{gathered}
$$



## Degree of polarization

$$
P_{l i n}^{\prime}\left(\mathrm{B}_{\|}\right)=\frac{1}{1+\left(\Omega_{\|} \tau_{0}\right)^{2}}, \quad P_{\text {lin }}^{\prime \prime}\left(\mathrm{B}_{\|}\right)=\frac{\Omega_{\|} \tau_{0}}{1+\left(\Omega_{\|} \tau_{0}\right)^{2}}
$$




Resonant optical orientation and alignment of excitons in QWs



At circularly polarized excitation longitudinal fields have no effect on the exciton orientation

Transversal field suppresses the orientation and can induce linear polarization

$$
\begin{aligned}
& P_{c}\left(\mathrm{~B}_{\perp}\right)=\frac{1}{1+\frac{3}{4}\left(\Omega_{\perp} \tau_{0}\right)^{2}} \\
& P_{\text {lin }}^{\prime}=\frac{\left(\Omega_{\perp} \tau_{0}\right)^{2}}{4+3\left(\Omega_{\perp} \tau_{0}\right)^{2}}
\end{aligned}
$$

## Transformation of polarizations in QDs

$$
P_{c}=>\rho_{l}
$$


-Specific of excitons is that for exciton additionally to optical orientation we have optical alignment of dipole momenta.
-The mechanisms for exciton spin relaxation are different from that for electrons

